

### Features

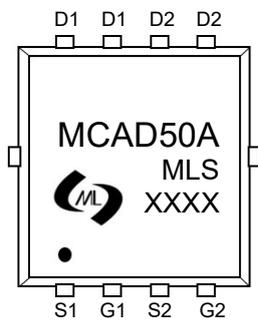
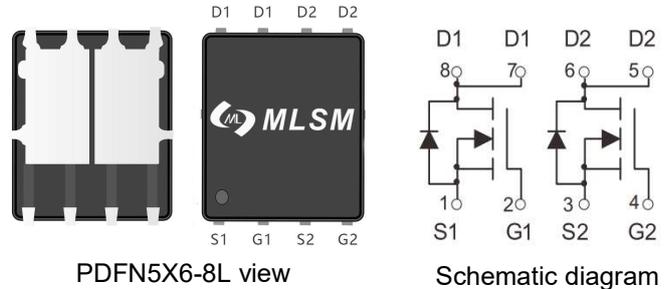
- High density cell design for ultra low  $R_{DS(ON)}$
- Fully characterized avalanche voltage and current
- Excellent package for good heat dissipation

### Product Summary

| $V_{DS}$ | $R_{DS(ON)}$ MAX   | $I_D$ MAX |
|----------|--------------------|-----------|
| 30V      | 7.5m $\Omega$ @10V | 50A       |
|          | 12m $\Omega$ @4.5V |           |

### Application

- High current load applications
- Load switch
- Hard switched and high frequency circuits



MCAD50A : Device code  
 XXXX : Code

Marking and pin assignment



### Absolute Maximum Ratings (TA=25°C unless otherwise noted)

| Symbol | Parameter | Rating | Unit |
|--------|-----------|--------|------|
|--------|-----------|--------|------|

### Common Ratings (TC=25°C Unless Otherwise Noted)

|           |                                  |                         |             |
|-----------|----------------------------------|-------------------------|-------------|
| $V_{DS}$  | Drain-Source Breakdown Voltage   | 30                      | V           |
| $V_{GS}$  | Gate-Source Voltage              | $\pm 20$                | V           |
| $T_J$     | Maximum Junction Temperature     | 150                     | $^{\circ}C$ |
| $T_{STG}$ | Storage Temperature Range        | -50 to 155              | $^{\circ}C$ |
| $I_S$     | Diode Continuous Forward Current | $T_c=25^{\circ}C$<br>50 | A           |

### Mounted on Large Heat Sink

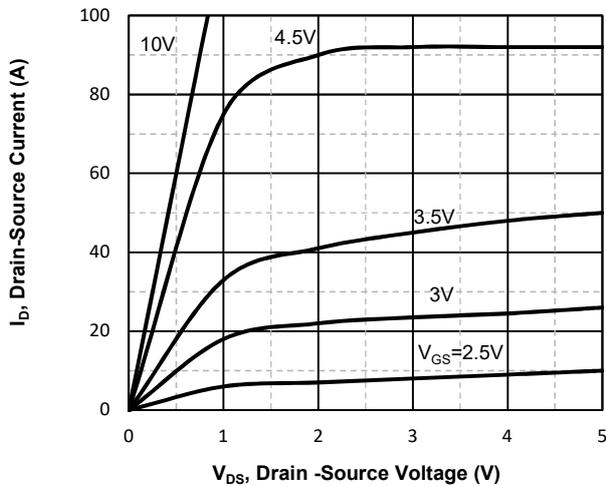
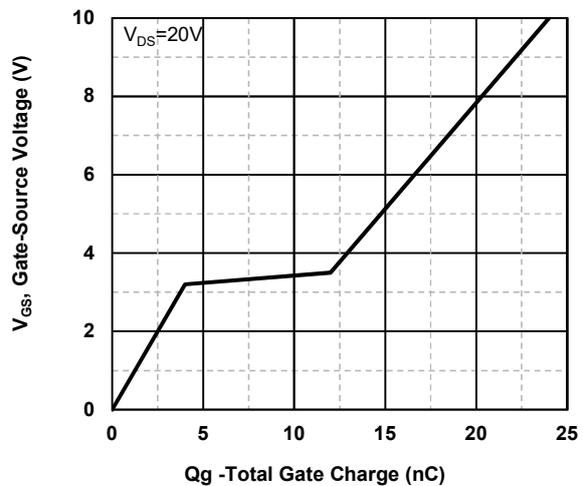
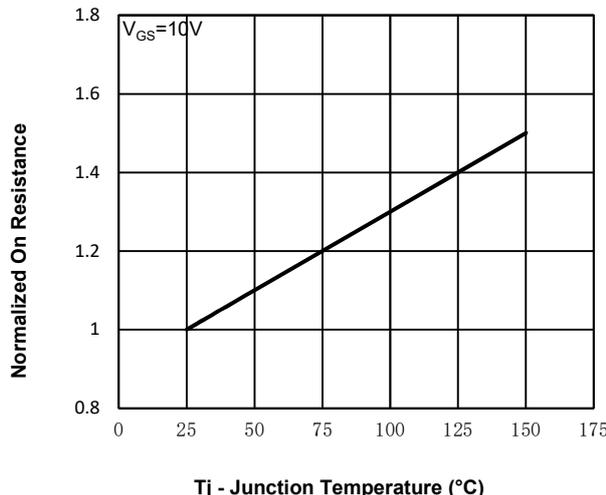
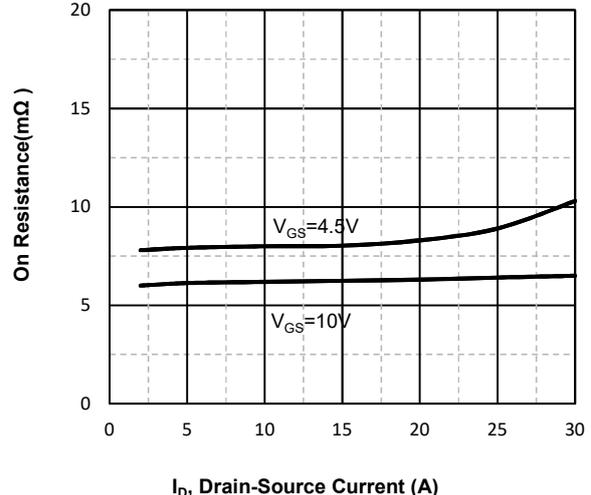
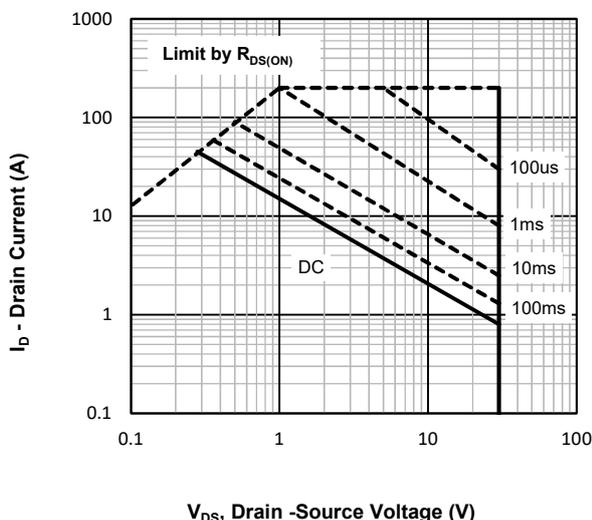
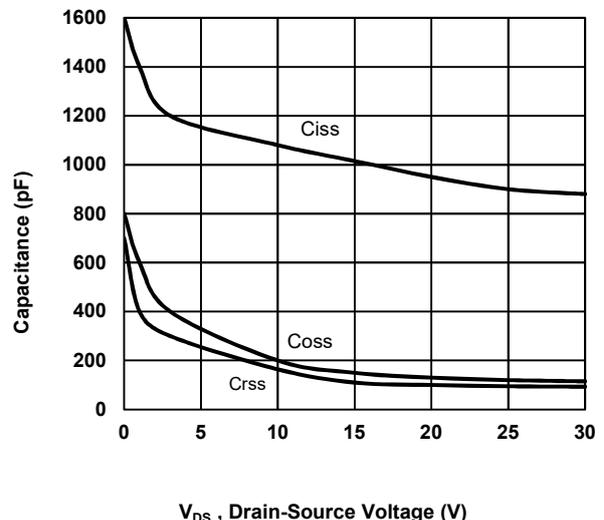
|                 |                                     |                          |               |
|-----------------|-------------------------------------|--------------------------|---------------|
| $I_{DM}$        | Pulse Drain Current Tested          | $T_c=25^{\circ}C$<br>200 | A             |
| $I_D$           | Continuous Drain Current            | $T_c=25^{\circ}C$<br>50  | A             |
| $P_D$           | Maximum Power Dissipation           | $T_c=25^{\circ}C$<br>35  | W             |
| $R_{\theta JA}$ | Thermal Resistance Junction-Ambient | 65                       | $^{\circ}C/W$ |

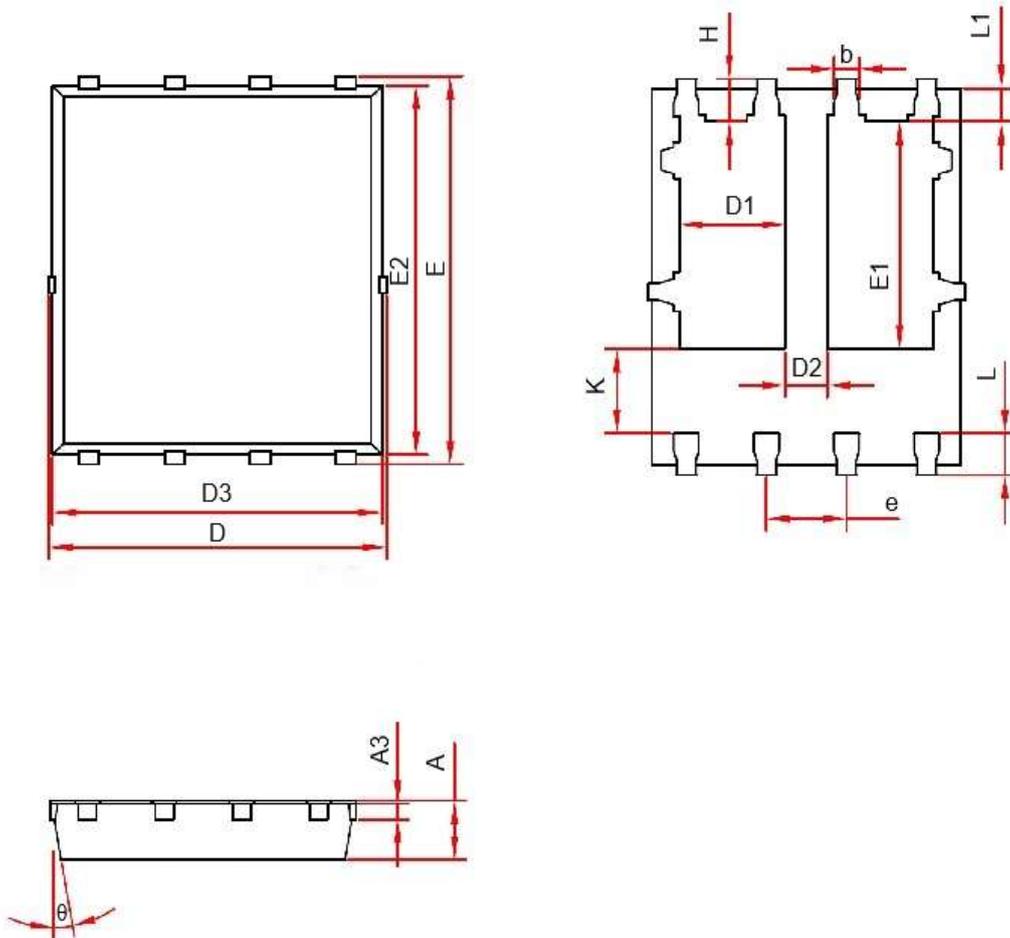
### Ordering Information (Example)

| Type    | Package    | Marking | Minimum Package(pcs) | Inner Box Quantity(pcs) | Outer Carton Quantity(pcs) | Delivery Mode |
|---------|------------|---------|----------------------|-------------------------|----------------------------|---------------|
| MCAD50A | PDFN5X6-8L | MCAD50A | 5,000                | 10,000                  | 70,000                     | 13"reel       |



| Electrical Characteristics (T <sub>J</sub> =25°C unless otherwise noted)                   |                                  |                                                                                        |     |      |      |      |
|--------------------------------------------------------------------------------------------|----------------------------------|----------------------------------------------------------------------------------------|-----|------|------|------|
| Symbol                                                                                     | Parameter                        | Condition                                                                              | Min | Typ  | Max  | Unit |
| <b>Static Electrical Characteristics @ T<sub>J</sub> = 25°C (unless otherwise stated)</b>  |                                  |                                                                                        |     |      |      |      |
| BV <sub>(BR)DSS</sub>                                                                      | Drain-Source Breakdown Voltage   | V <sub>GS</sub> =0V, I <sub>D</sub> =250μA                                             | 30  | --   | --   | V    |
| I <sub>DSS</sub>                                                                           | Zero Gate Voltage Drain Current  | V <sub>DS</sub> =30V, V <sub>GS</sub> =0V                                              | --  | --   | 1    | μA   |
| I <sub>GSS</sub>                                                                           | Gate-Body Leakage Current        | V <sub>GS</sub> =±20V, V <sub>DS</sub> =0V                                             | --  | --   | ±100 | nA   |
| V <sub>GS(th)</sub>                                                                        | Gate Threshold Voltage           | V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =250μA                               | 1.0 | 1.5  | 2.5  | V    |
| R <sub>DS(on)</sub>                                                                        | Drain-Source On-State Resistance | V <sub>GS</sub> =10V, I <sub>D</sub> =25A                                              | --  | 6    | 7.5  | mΩ   |
|                                                                                            |                                  | V <sub>GS</sub> =4.5V, I <sub>D</sub> =10A                                             | --  | 7.8  | 12   | mΩ   |
| <b>Dynamic Electrical Characteristics @ T<sub>J</sub> = 25°C (unless otherwise stated)</b> |                                  |                                                                                        |     |      |      |      |
| C <sub>ISS</sub>                                                                           | Input Capacitance                | V <sub>DS</sub> =15V, V <sub>GS</sub> =0V, f=1MHz                                      | --  | 1015 | --   | pF   |
| C <sub>OSS</sub>                                                                           | Output Capacitance               |                                                                                        | --  | 201  | --   | pF   |
| C <sub>RSS</sub>                                                                           | Reverse Transfer Capacitance     |                                                                                        | --  | 164  | --   | pF   |
| <b>Switching Characteristics</b>                                                           |                                  |                                                                                        |     |      |      |      |
| Q <sub>g</sub>                                                                             | Total Gate Charge                | V <sub>DS</sub> =20V, I <sub>D</sub> =10A,<br>V <sub>GS</sub> =10V                     | --  | 23.6 | --   | nC   |
| Q <sub>gs</sub>                                                                            | Gate Source Charge               |                                                                                        | --  | 3.9  | --   | nC   |
| Q <sub>gd</sub>                                                                            | Gate Drain Charge                |                                                                                        | --  | 7    | --   | nC   |
| td(on)                                                                                     | Turn-on Delay Time               | V <sub>DS</sub> =20V, I <sub>D</sub> =10A,<br>V <sub>GS</sub> =10V, R <sub>G</sub> =3Ω | --  | 7    | --   | nS   |
| tr                                                                                         | Turn-on Rise Time                |                                                                                        | --  | 19   | --   | nS   |
| td(off)                                                                                    | Turn-Off Delay Time              |                                                                                        | --  | 24   | --   | nS   |
| tf                                                                                         | Turn-Off Fall Time               |                                                                                        | --  | 24   | --   | nS   |
| <b>Source- Drain Diode Characteristics</b>                                                 |                                  |                                                                                        |     |      |      |      |
| V <sub>SD</sub>                                                                            | Forward on voltage               | T <sub>J</sub> =25°C, I <sub>S</sub> =10A                                              | --  | --   | 1.2  | V    |

**Typical Operating Characteristics**

**Fig1. Typical Output Characteristics**

**Fig2. Typical Gate Charge Vs. Gate-Source Voltage**

**Fig3. Normalized On-Resistance Vs. Temperature**

**Fig4. On-Resistance Vs. Drain-Source Current**

**Fig5. Maximum Safe Operating Area**

**Fig6. Typical Capacitance Vs. Drain-Source**

**PDFN5X6-8L Package information**


| Symbol   | Dimensions in Millimeters(mm) |       | Dimensions In Inches |       |
|----------|-------------------------------|-------|----------------------|-------|
|          | Min                           | Max   | Min                  | Max   |
| A        | 0.950                         | 1.050 | 0.035                | 0.039 |
| A3       | 0.254REF.                     |       | 0.010REF.            |       |
| D        | 4.950                         | 5.050 | 0.196                | 0.200 |
| E        | 5.950                         | 6.050 | 0.235                | 0.239 |
| D1       | 1.470                         | 1.870 | 0.058                | 0.074 |
| D2       | 0.470                         | 0.870 | 0.019                | 0.034 |
| E1       | 3.510                         | 3.610 | 0.139                | 0.143 |
| D3       | 4.850                         | 4.950 | 0.192                | 0.196 |
| E2       | 5.700                         | 5.800 | 0.225                | 0.229 |
| k        | 1.190                         | 1.390 | 0.047                | 0.055 |
| b        | 0.300                         | 0.400 | 0.012                | 0.016 |
| e        | 1.270TYP.                     |       | 0.050TYP.            |       |
| L        | 0.559                         | 0.711 | 0.022                | 0.028 |
| L1       | 0.424                         | 0.576 | 0.017                | 0.023 |
| H        | 0.574                         | 0.726 | 0.023                | 0.029 |
| $\theta$ | 10°                           | 12°   | 10°                  | 12°   |